Fineon

Lehman Brothers T-4 2004 Conference

San Francisco – December 9, 2004

Mark Tyndall

Vice President, IR & Business Development

Achim Schneider

Senior Director, IR & Financial Communications



Never stop thinking.



Disclaimer

Please note that while you are reviewing this information, this presentation was created as of the date listed, and reflected management views as of that date.

This presentation contains certain forward-looking statements that are subject to known and unknown risks and uncertainties that could cause actual results to differ materially from those expressed or implied by such statements. Such risks and uncertainties include, but are not limited to the Risk Factors noted in the Company's Earnings Releases and the Company's filings with the Securities and Exchange Commission.



Agenda



Regional Strategy

Business Group Highlights

Infineon's Integrated Business Model



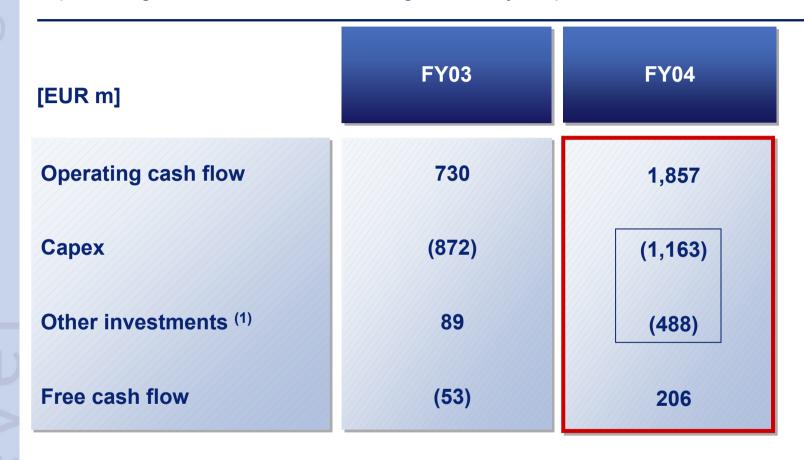


Financial and Market Development FY04 vs. FY03

[EUR m]	FY03	FY04	Change
Net sales Growth (%)	6,152	7,195	+1,043 +17%
Gross margin	25%	35%	
R&D in % of sales	1,089 18%	1,219 17%	+130
SG&A in % of sales	679 11%	718 10%	+39
EBIT in % of sales	(299) (5%)	256 4%	+555
Therein impairment and antitrust-related charges	(126)	(345)	



Solid Financial Position – Operating and free cash flow significantly improved



➤ Solid gross cash position of EUR 2.546 billion at Sept 30th, with a Net cash position of EUR 548 million



Outlook for first quarter of fiscal year 2005

- > Expectations for a slowdown in several application segments due to higher inventory levels compared to the previous quarters.
- For automotive electronics, continuing price pressure and no major changes in demand for semiconductors expected, but weaker market for the industrial segment. In combination with seasonal effects, slight reduction in revenues and earnings expected.
- In Wireline Communications no growth expected due to continuing pricing pressure and marketplace inventory corrections. EBIT loss expected to be significantly reduced if and when sale of Fibre Optics to Finisar is closed.
- For **Secure Mobile Solutions** significant reduction in revenues anticipated, driven mainly by market slowdown and higher inventories in the Asian mobile phone market.
- For **Memory Products** business in line with normal seasonal demand expected. Based on additional capacities from Inotera joint venture, Infineon anticipates an increase of bit production.
- Non-recurring USD 153 million license income from ProMOS agreement expected to positively impact the quarter.



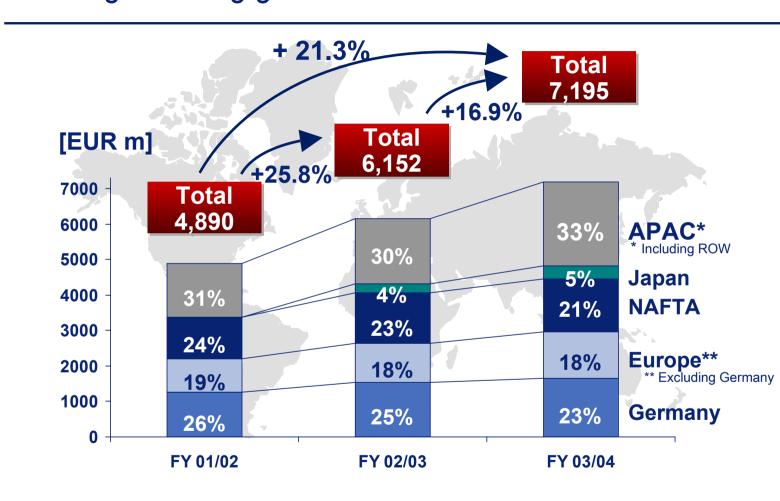


Financial Update and Outlook	
------------------------------	--

- Regional Strategy
- **Business Group Highlights**
- Infineon's Integrated Business Model



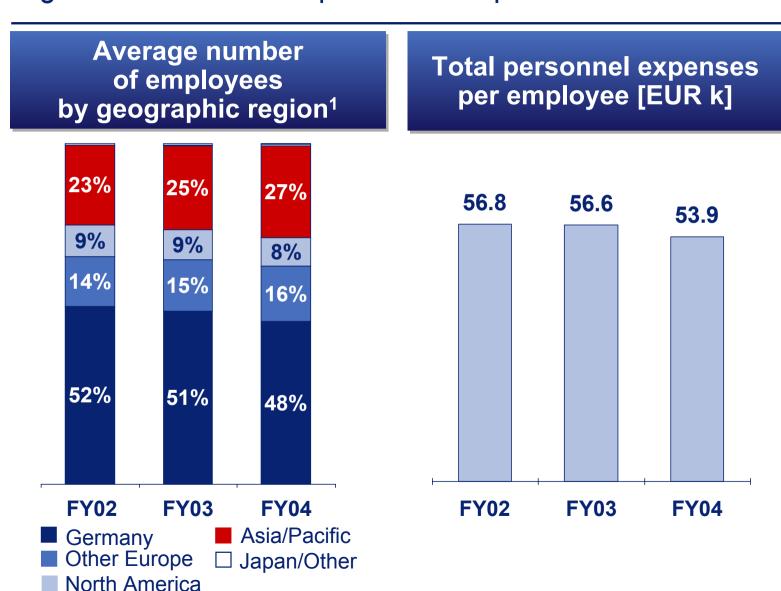
Our focus and investments in Asia and Japan continues resulting in strong growth



➤ **Dec 8**th **announcement**: Infineon to build new fab for power semiconductors, targeted at Automotive & Industrial applications in Kulim High Tech Park, Malaysia, representing an USD 1 billion investment in the next years



Increasing proportion of employees in lower-cost regions leads to lower personnel expenses





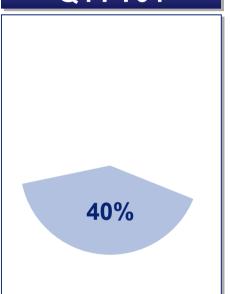
Financial Undata and Outlook
Financial Undate and Outlook
Thirding and option and outlook

- Regional Strategy
- **Business Group Highlights**
- Infineon's Integrated Business Model



Memory Products: Significant margin improvement with focus now on shrink acceleration to 90 nm





Revenues and EBIT margin



- Sequential revenue decrease was mainly caused by a lower ASP and a weakening US-Dollar, which could not be completely compensated by higher sales volumes.
- Sequential EBIT increase before antitrust-related charges was driven by higher bit shipments in combination with cost reductions attributable to a higher 110nm technology share that was more than offsetting the price decline during the quarter.



110nm technology: In volume production 90nm and 70nm: Qualification at customers and in pipelin

70nm

Key facts on 110nm:

- Best wafer yield >93.9%
- Know-how in 193nm litho extended
- All process parameters well established
- More than 80% of all capacities converted to 110nm end FY04

Node	Status	
110nm	- Mass production	
	O distribution of the second	256M DDR

Key innovations in 90nm and 70nm:

- 90nm: New cell layoutBottle-shaped trench
- 70nm: High-κ fill in trench

Node	Status
90nm	Customer samples from 200mm: 512M DDRTransfer to 300m line
	- Ramp-up expected
	mid 2005

- First demonstrators

on 300mm: 512M DDR2



110nm: Basis for global 300mm ramp-up in 2005 with 90nm to ramp in 300mm





Benefit through alliances with partners



- Investment of about USD 2.2 billion
- Capacity of 24,000 WSPM reached
 2 months ahead of schedule in
 October 2004 (50:50 for JV partners)
- 300mm capacity of up to 54,000 WSPM by end of 2005 (50:50 for JV partners)
- First products: 256M DDR and 512M DDR2 in 110nm technology
- Largest DRAM manufacturing module worldwide when completed end of 2005

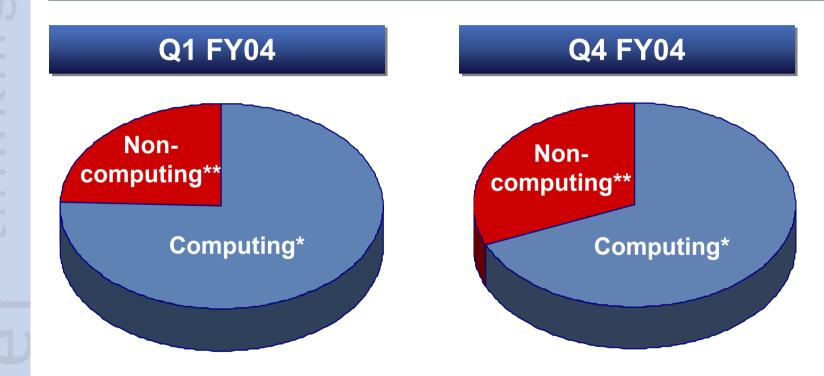
Memory development center in Dresden

- Approximately 400 employees including 50 from Nanya
- Technology development relocated: DRAM 90nm and 70nm
- Focusing development in 300mm line





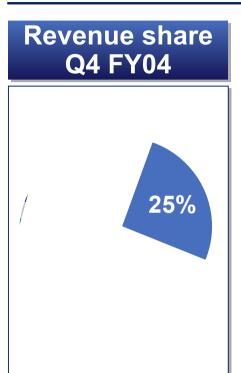
Bit shipment share of non-computing applications increased to more than 30% in Q4 FY04

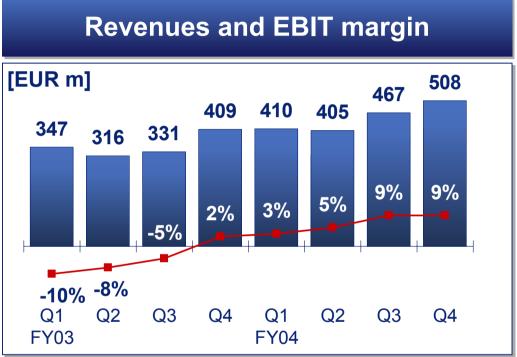


- * Desktop PCs, Notebooks and Workstations; ** Infrastructure, Consumer, Mobile Applications
 - ⇒ A leading supplier to server manufacturers
 - ⇒ Leading with Mobile-RAMs, with Cellular RAM solution
 - ⇒ Increasing shipments of Graphics RAM GDDR3 @ 500Mhz
 - □ Increasing share of shipments for set-top boxes



Secure Mobile Solutions: Strong revenue growth and EBIT margin improvement





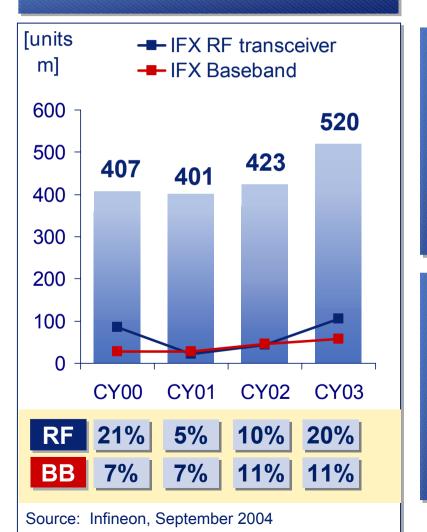
Sequential revenue improvement was mainly driven by higher demand for mobile solutions. Mobile phone manufacturers have aggressively purchased components in anticipation of a strong holiday season.



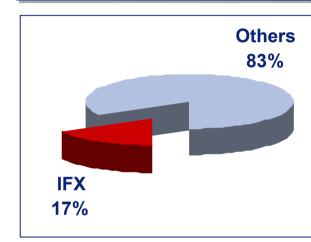
Continued to gain market share in RF and baseband

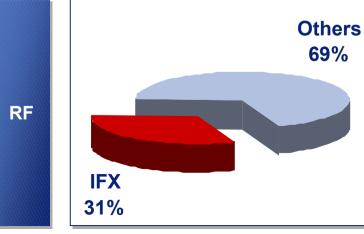
BB

Total handset market CY00 to CY03



GSM/GPRS/EDGE Based







Infineon leading the introduction of RF CMOS as mainstream technology for all RF transceivers

RF CMOS benefits:

- Efficient and simple digital circuitry
- Takes advantage of CMOS shrink potential
- Enables RF/Baseband integration roadmap
- Synergies with mainstream production technologies

Customer benefits:

- Reduced power consumption
- BOM savings
- Fastest time to market
- Increased manufacturing flexibility



Next step: Monolithic integration

2004 2005

RF CMOS transceiver:

- Volume production
- 130nm CMOS
- Single-chip digital RF solution

Baseband:

- Volume production
- 130nm CMOS
- Integrates:
 - Digital baseband
 - Mixed signal
 - SRAM



- Lower system cost
- Smaller PCB area
- Less complexity

Single-chip: RF and baseband





Infineon wireless product and service offering

Design and consulting center

Mobile phone platform package

Chipset

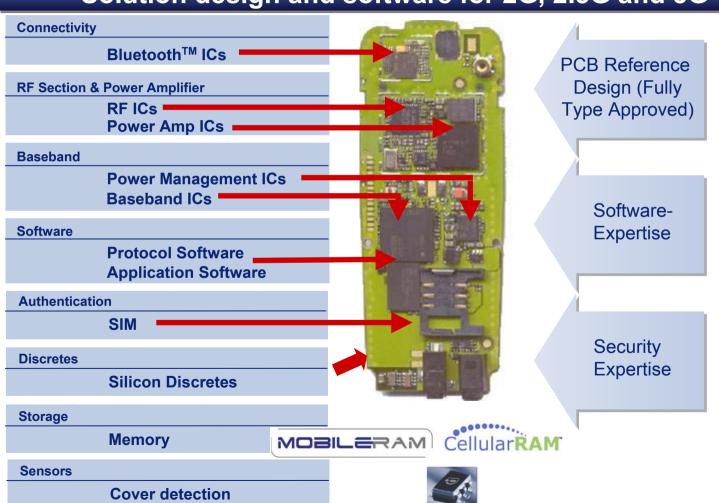


Customer



Infineon providing up to 80% of silicon content in customized solution platforms for our customers

Solution design and software for 2G, 2.5G and 3G





Well positioned with > 41% market share on Smart Card serving the key growth markets

Contactbased chip cards Contactless chip cards, RFID

Security ICs



CommunicationsPrepaid
Mobile







Payment
Credit/Debit, e-purse
Transport, ticketing







Identification ePassport, nat. ID, social, access, RFID, e-Government









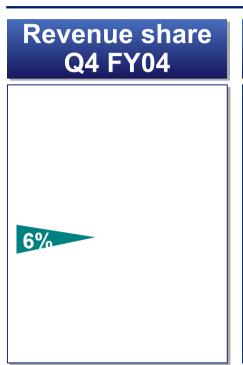
Entertainment Pay TV, gaming, video/audio

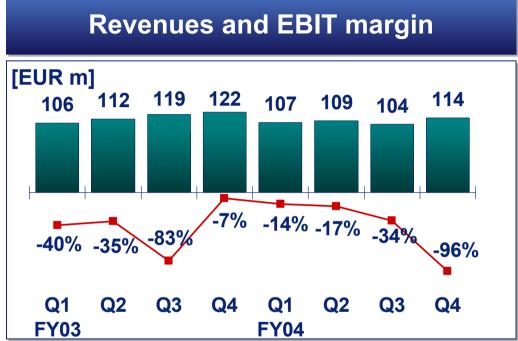






Wireline Communications: Strategic measures initiated to achieve profitability

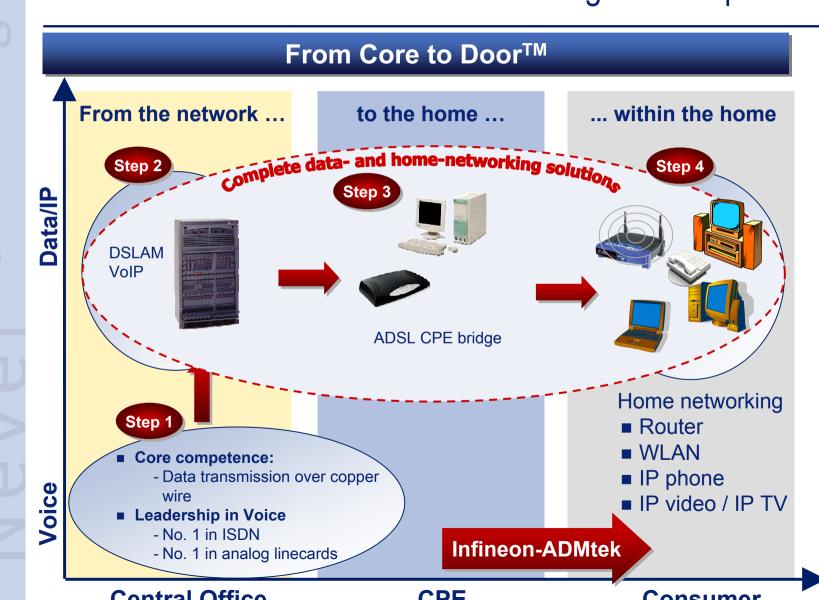




- Sequential revenue increase was mainly driven by higher sales of broadband access ADSL products.
- EBIT loss increased sequentially mainly due to impairment charges of EUR 80 million, predominantly related to the acquisition of Catamaran Communications, Inc.



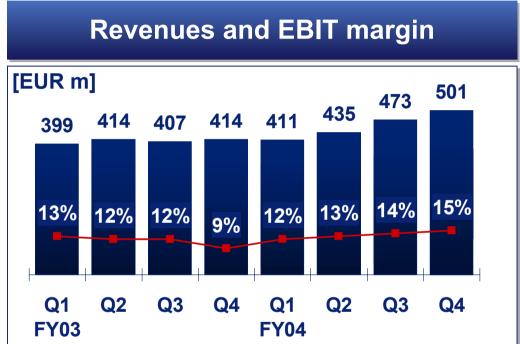
Transforming from the leading traditional telecom voice vendor into a data- and home-networking solution provide





Automotive & Industrial: Record revenues and stable margins at a high level



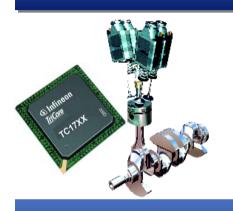


Sequential revenue increase was mostly due to increased sales of products for power management & supply, high-power applications and sensors.



Al – Complete coverage of customers' needs

Defining automotive intelligence



Applications:

- Powertrain
- Safety management
- Body & convenience
- Infotainment

Products:

- Sensors
- Microcontrollers
- Power devices
- Silicon discretes



Converting and controlling power



Applications:

- AC/DC conversion
- DC/DC conversion
- Consumer drives
- General-purpose drive

Products:

- Sensors
- Microcontrollers
- Thyristors / diodes
- Discrete power
- IGBT modules and bipolar modules
- Power ICs
- Silicon discretes





Leading positions by increasing market shares in both segments



Infineon Automotive 2003 No. 2 World, No. 1 EU, No. 3 U.S. Infineon Power 2003*
No. 1 World, No. 1 EU, No. 4 U.S.

			2003	2002
	1.	Freescale	12.9%	13.4%
4	2.	Infineon (2)	8.7%	8.2%
	3.	STM	7.6%	6.6%
	4.	Renesas	7.0%	n.a.
	5.	Bosch	6.4%	5.2%
	6.	Toshiba	6.1%	6.2%
	7.	NEC	6.0%	6.1%
	8.	Philips	5.7%	5.9%

		2003	2002
1.	Infineon (4)	8.1%	6.6%
2.	IR	8.0%	7.6%
3.	STM	7.9%	6.3%
4.	Fairchild	7.4%	6.7%
5.	Toshiba	7.2%	8.6%
6.	Vishay	6.1%	6.3%
7.	Renesas	5.0%	n.a.
8.	Fuji	5.0%	4.0%

■ Market: USD 13.1 billion

■ 5 yr CAGR: +7-8%

Source: Strategy Analytics, 2004/IMS 2004

■ Market: USD 9.4 billion

■ 5 yr CAGR: +10%

^{*} Business Unit "Discrete Power"



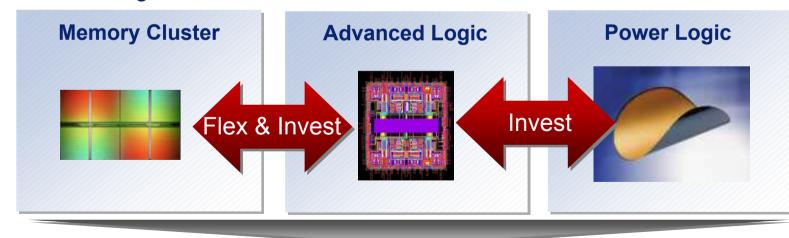
- Financial Update and Outlook
- Regional Strategy
- **Business Group Highlights**
- Infineon's Integrated Business Model



Integrated manufacturing to maximize our flexibility and minimize cost

Maximize: Opportunities during market upturns Minimize: Impact of downturns and investments

- Internal flexibility: Between MP and Advanced Logic Cluster
- External flexibility: Silicon foundries and subcontractors
- Cost optimization: Reuse of depreciated equipment for power technologies



Flexibility: Silicon foundries and subcontractors





Never stop thinking.